

DATA SHEET

TZA3043

**Gigabit Ethernet/Fibre Channel
transimpedance amplifier**

Objective specification
File under Integrated Circuits, IC19

1998 Jul 08

Gigabit Ethernet/Fibre Channel transimpedance amplifier TZA3043

FEATURES

- Wide dynamic range, typically 2.5 μ A to 1.5 mA
- Differential transimpedance of 14 k Ω
- Wide bandwidth of 950 MHz
- Differential outputs
- On-chip AGC (Automatic Gain Control)
- No external components required
- Single supply voltage from 3.0 to 5.5 V
- Bias voltage for PIN diode
- Pin compatible with TZA3023 and SA5223.

APPLICATIONS

- Digital fibre optic receiver in medium and long haul optical telecommunications transmission systems or in high speed data networks
- Wideband RF gain block.

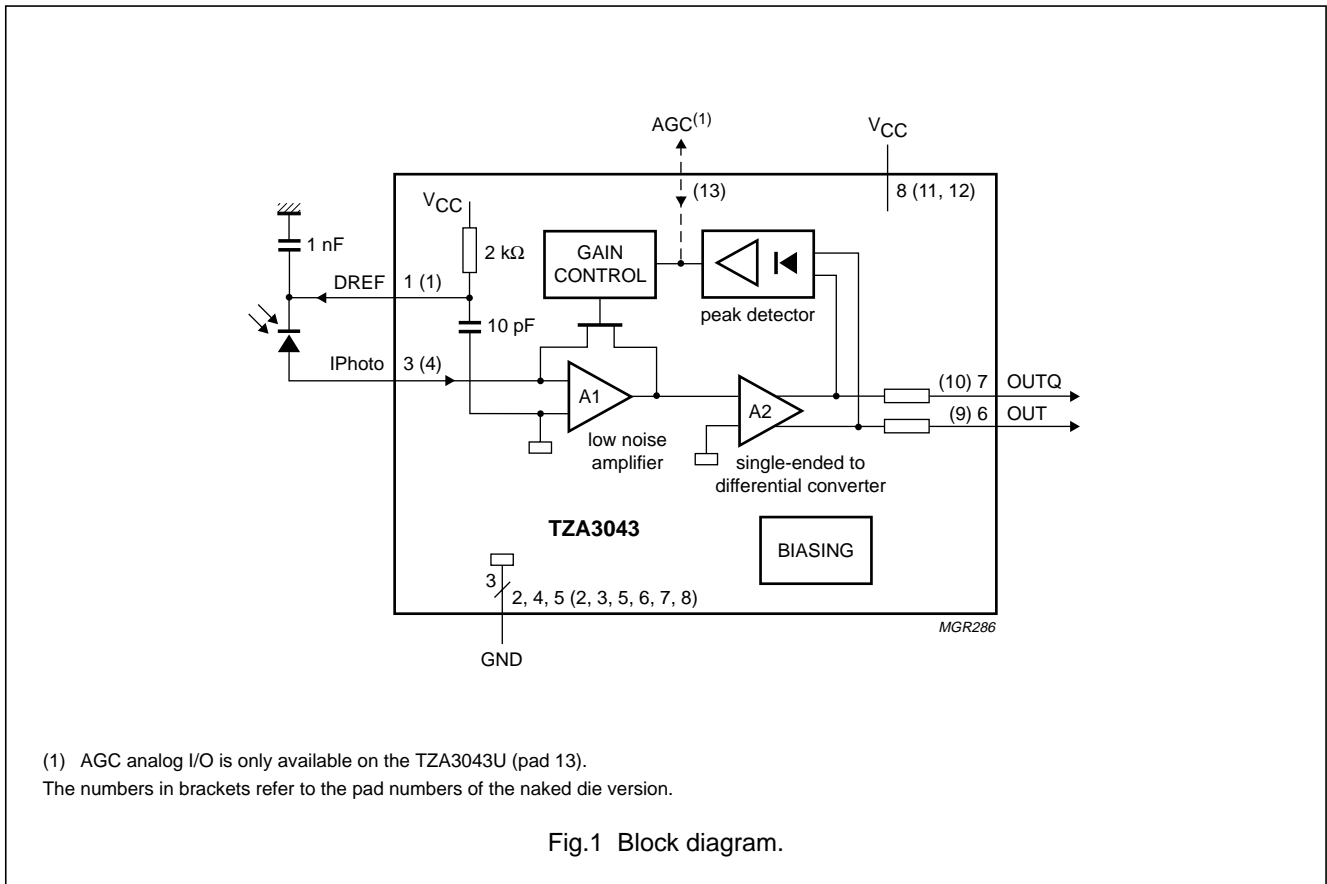
DESCRIPTION

The TZA3043 is a high speed transimpedance amplifier with AGC designed to be used in Gigabit Ethernet/Fibre Channel optical links. It amplifies the current generated by a photo detector (PIN diode or avalanche photodiode) and converts it to a differential output voltage.

ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
TZA3043T	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1
TZA3043U	naked die	die in wafer pack carriers; die dimensions 0.960 \times 1.210 mm	–

BLOCK DIAGRAM

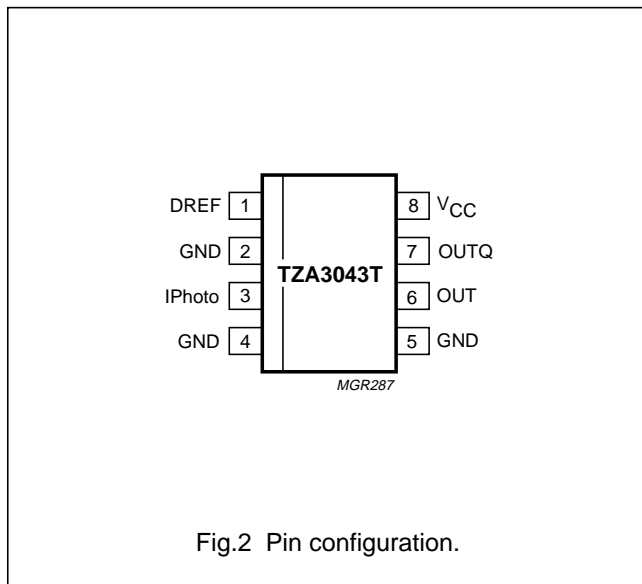


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PINNING

SYMBOL	PIN	TYPE	DESCRIPTION
DREF	1	analog output	bias voltage for PIN diode (V_{CC}); cathode should be connected to this pin
GND	2	ground	ground
IPhoto	3	analog input	current input; anode of PIN diode should be connected to this pin; DC bias level of 822 mV is one diode voltage above ground
GND	4	ground	ground
GND	5	ground	ground
OUT	6	data output	data output; OUT goes HIGH when current flows into IPhoto (pin 3)
OUTQ	7	data output	compliment of OUT (pin 6)
V_{CC}	8	supply	supply voltage



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PAD CONFIGURATION

Bonding pad locations

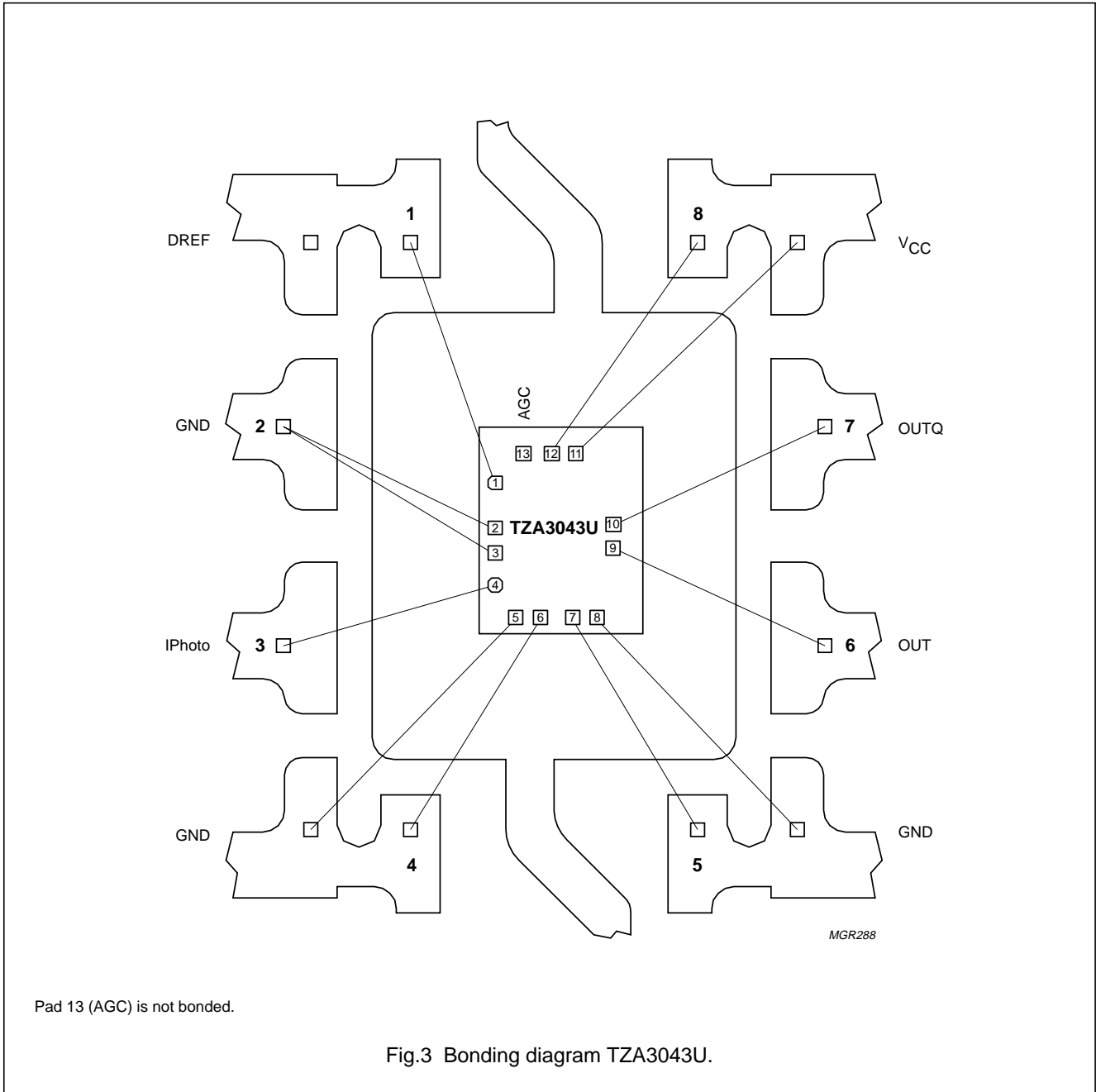


Fig.3 Bonding diagram TZA3043U.

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Pad centre locations

SYMBOL	PAD	COORDINATES ⁽¹⁾	
		x	y
DREF	1	95	881
GND	2	95	618
GND	3	95	473
IPhoto	4	95	285
GND	5	215	95
GND	6	360	95
GND	7	549	95
GND	8	691	95
OUT	9	785	501
OUTQ	10	785	641
V _{CC}	11	567	1055
V _{CC}	12	424	1055
AGC	13	259	1055

Note

- All coordinates (μm) are measured with respect to the bottom left-hand corner of the die.

FUNCTIONAL DESCRIPTION

The TZA3043 is a transimpedance amplifier intended for use in fibre optic links for signal recovery in Fibre Channel applications. It amplifies the current generated by a photo detector (PIN diode or avalanche photodiode) and transforms it into a differential output voltage. The most important characteristics of the TZA3043 are high receiver sensitivity and wide dynamic range. High receiver sensitivity is achieved by minimizing noise in the transimpedance amplifier.

Input circuit

The signal current generated by a PIN diode can vary between 2.5 μA to 1.5 mA (peak-to-peak value).

An AGC loop (see Fig.1) is implemented to make it possible to handle such a wide dynamic range. The AGC loop increases the dynamic range of the receiver by reducing the feedback resistance of the preamplifier. The AGC loop hold capacitor is integrated on-chip, so an external capacitor is not needed for AGC.

AGC monitoring

The AGC voltage can be monitored at pad 13 on the naked die (TZA3043U). Pad 13 is not bonded in the packaged device (TZA3043T). This pad can be left unconnected during normal operation. It can also be used to force an external AGC voltage. If pad 13 (AGC) is connected to GND, the internal AGC loop is disabled and the receiver gain is at a maximum. The maximum input current is then about 75 μA .

Output circuit

The differential amplifier A2 converts the output of the preamplifier A1 to a differential voltage (see Fig.4).

The logic level symbol definitions for the differential outputs are shown in Fig.5.

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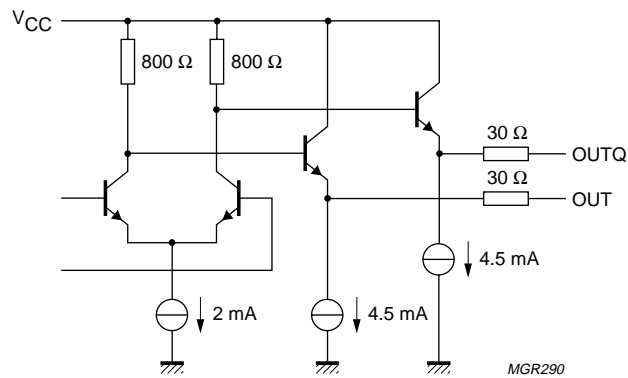


Fig.4 Differential data output circuit.

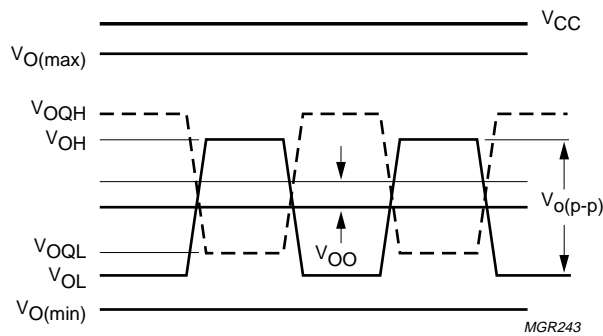


Fig.5 Logic level symbol definitions for data outputs OUT and OUTQ.

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V_{CC}	supply voltage	-0.5	+5.5	V
V_n	DC voltage			
	pin 3/pad 4: IPhoto	-0.5	+1	V
	pins 6 and 7/pads 9 and 10: OUT and OUTQ	-0.5	$V_{CC} + 0.5$	V
	pad 13: AGC (TZA3043U only)	-0.5	$V_{CC} + 0.5$	V
	pin 1/pad 1: DREF	-0.5	$V_{CC} + 0.5$	V
I_n	DC current			
	pin 3/pad 4: IPhoto	-2.5	+2.5	mA
	pins 6 and 7/pads 9 and 10: OUT and OUTQ	-15	+15	mA
	pad 13: AGC (TZA3043U only)	-0.2	+0.2	mA
	pin 1/pad 1: DREF	-2.5	+2.5	mA
P_{tot}	total power dissipation	-	300	mW
T_{stg}	storage temperature	-65	+150	°C
T_j	junction temperature	-	150	°C
T_{amb}	ambient temperature	-40	+85	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
$R_{th(j-s)}$	thermal resistance from junction to solder point	tbF	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	tbF	K/W

CHARACTERISTICS

For typical values $T_{amb} = 25\text{ °C}$ and $V_{CC} = 5\text{ V}$; minimum and maximum values are valid over the entire ambient temperature range and process spread.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{CC}	supply voltage		3	5	5.5	V
I_{CC}	supply current	AC coupled; $R_L = 50\ \Omega$	-	35	62	mA
P_{tot}	total power dissipation	$V_{CC} = 5\text{ V}$	-	175	341	mW
		$V_{CC} = 3.3\text{ V}$	-	112	212	mW
T_j	junction temperature		-40	-	+110	°C
T_{amb}	ambient temperature		-40	+25	+85	°C
R_{tr}	small-signal transresistance of the receiver	measured differentially; AC coupled				
		$R_L = \infty$	-	29	-	k Ω
		$R_L = 50\ \Omega$	-	14.5	-	k Ω
$f_{-3dB(h)}$	high frequency -3 dB point	$V_{CC} = 5\text{ V}$; $C_i = 0.7\text{ pF}$	-	920	-	MHz
		$V_{CC} = 3.3\text{ V}$; $C_i = 0.7\text{ pF}$	-	800	-	MHz

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$I_{n(\text{tot})}$	total integrated RMS noise current over bandwidth	referred to input; $\Delta f = 920 \text{ MHz}$; note 1	–	200	–	nA
$\Delta R_{\text{tr}}/\Delta t$	AGC loop constant		–	1	–	dB/ms
PSRR	power supply rejection ratio	measured differentially; note 2 $f = 1 \text{ to } 100 \text{ MHz}$ $f = 1 \text{ GHz}$	–	2 66	–	$\mu\text{A/V}$ $\mu\text{A/V}$
Input: IPhoto						
$V_{\text{bias(IPhoto)}}$	input bias voltage on pin IPhoto		650	822	970	mV
$I_{\text{i(IPhoto)(p-p)}}$	input current on pin IPhoto (peak-to-peak value)	$V_{\text{CC}} = 5 \text{ V}$	–2000	+4	+2000	μA
		$V_{\text{CC}} = 3.3 \text{ V}$	–1000	+4	+1000	μA
Data outputs: OUT and OUTQ						
$V_{\text{O(CM)}}$	common mode output voltage	AC coupled; $R_{\text{L}} = 50 \ \Omega$	$V_{\text{CC}} - 1.800$	$V_{\text{CC}} - 1.700$	$V_{\text{CC}} - 1.600$	V
$V_{\text{o(se)(p-p)}}$	single-ended output voltage (peak-to-peak value)	AC coupled; $R_{\text{L}} = 50 \ \Omega$	150	200	260	mV
V_{OO}	differential output offset voltage		–30	–	+30	mV
R_{O}	output resistance	single-ended; DC tested	42	50	58	Ω
t_{r}	rise time	20% to 80%	–	200	tbf	ps
t_{f}	fall time	80% to 20%	–	200	tbf	ps

Notes

- All $I_{n(\text{tot})}$ measurements were made with an input capacitance of $C_{\text{i}} = 1 \text{ pF}$. This was comprised of 0.5 pF for the photodiode itself, with 0.3 pF allowed for the printed-circuit board layout and 0.2 pF intrinsic to the package.
- PSRR is defined as the ratio of the equivalent current change at the input (ΔI_{IPhoto}) to a change in supply voltage:

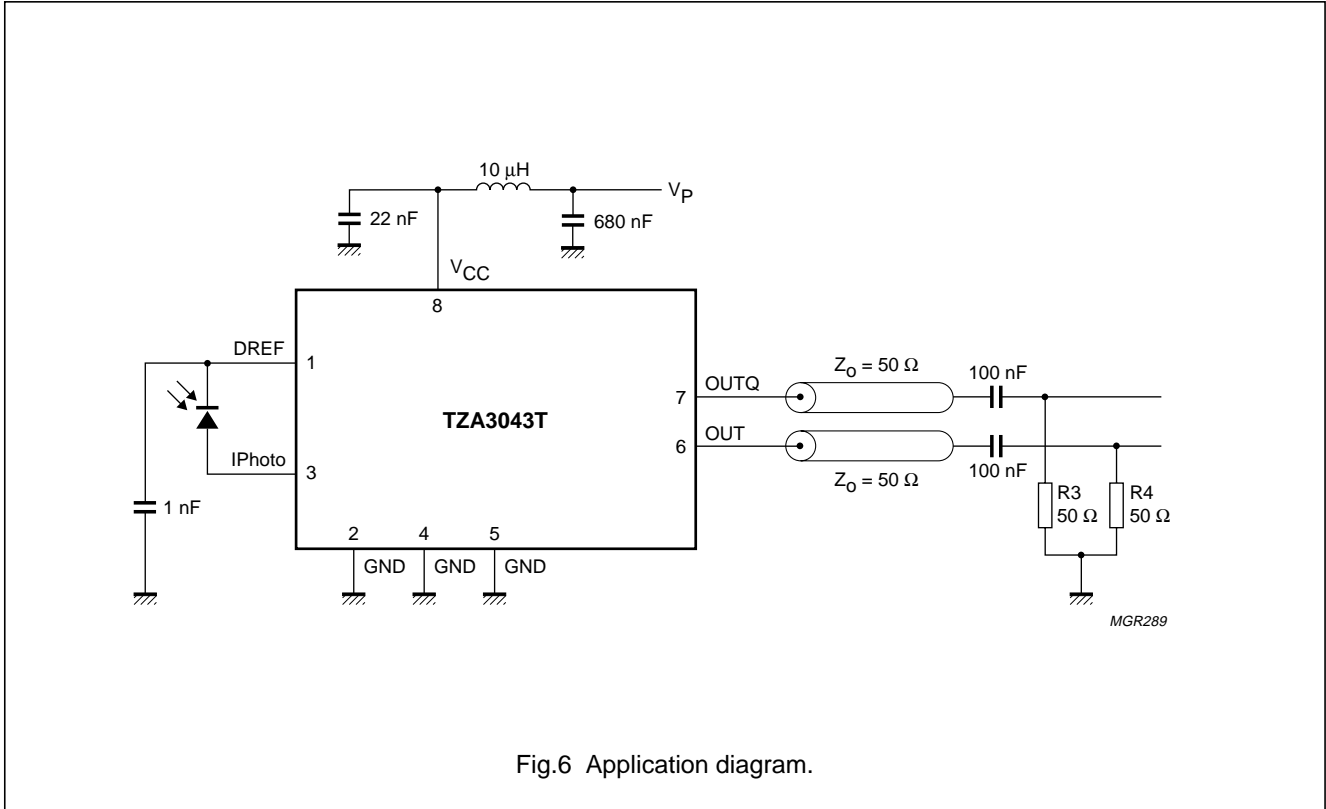
$$\text{PSRR} = \frac{\Delta I_{\text{IPhoto}}}{\Delta V_{\text{CC}}}$$

For example, a disturbance of +10 mV on V_{CC} at 10 MHz will typically add an extra 20 nA to the photodiode current. The external capacitor between pin DREF and pin GND has a large impact on PSRR. The specification is valid with an external capacitor of 1 nF.

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APPLICATION INFORMATION



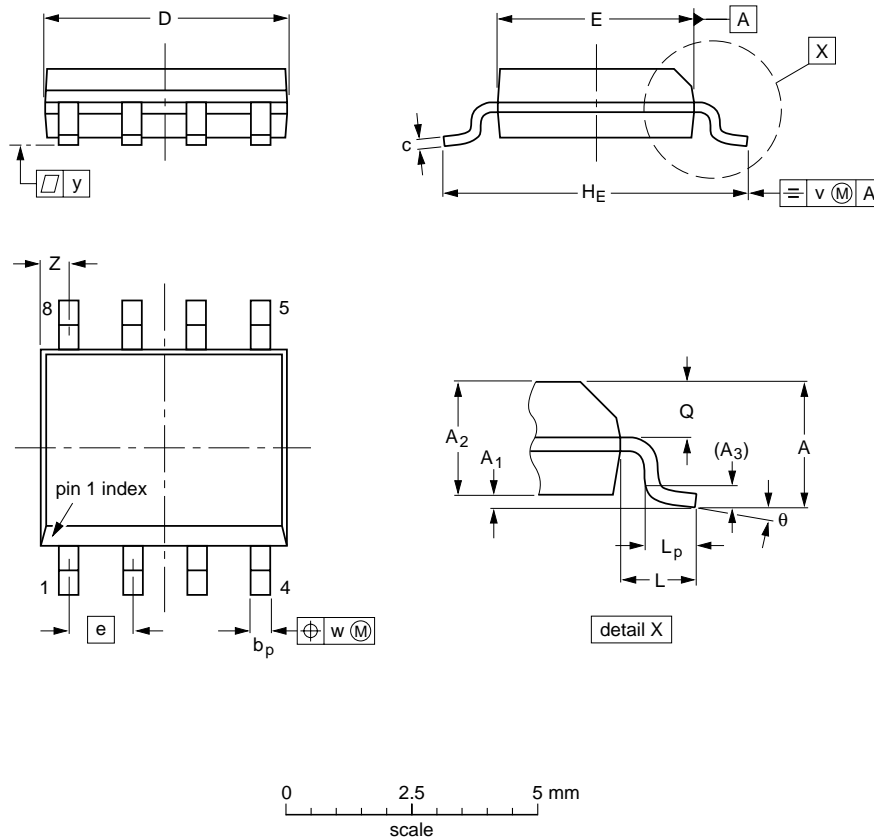
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PACKAGE OUTLINE

SO8: plastic small outline package; 8 leads; body width 3.9 mm

SOT96-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽²⁾	e	H _E	L	L _p	Q	v	w	y	z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	5.0 4.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8° 0°
inches	0.069	0.010 0.004	0.057 0.049	0.01	0.019 0.014	0.0100 0.0075	0.20 0.19	0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT96-1	076E03S	MS-012AA				95-02-04 97-05-22

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SOLDERING

Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (order code 9398 652 90011).

Reflow soldering

Reflow soldering techniques are suitable for all SO packages.

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several techniques exist for reflowing; for example, thermal conduction by heated belt. Dwell times vary between 50 and 300 seconds depending on heating method. Typical reflow temperatures range from 215 to 250 °C.

Preheating is necessary to dry the paste and evaporate the binding agent. Preheating duration: 45 minutes at 45 °C.

Wave soldering

Wave soldering techniques can be used for all SO packages if the following conditions are observed:

- A double-wave (a turbulent wave with high upward pressure followed by a smooth laminar wave) soldering technique should be used.
- The longitudinal axis of the package footprint must be parallel to the solder flow.
- The package footprint must incorporate solder thieves at the downstream end.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Maximum permissible solder temperature is 260 °C, and maximum duration of package immersion in solder is 10 seconds, if cooled to less than 150 °C within 6 seconds. Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

Repairing soldered joints

Fix the component by first soldering two diagonally-opposite end leads. Use only a low voltage soldering iron (less than 24 V) applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C. When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

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NOTES

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Philips Semiconductors – a worldwide company

Argentina: see South America

Australia: 34 Waterloo Road, NORTH RYDE, NSW 2113, Tel. +61 2 9805 4455, Fax. +61 2 9805 4466

Austria: Computerstr. 6, A-1101 WIEN, P.O. Box 213, Tel. +43 160 1010, Fax. +43 160 101 1210

Belarus: Hotel Minsk Business Center, Bld. 3, r. 1211, Volodarski Str. 6, 220050 MINSK, Tel. +375 172 200 733, Fax. +375 172 200 773

Belgium: see The Netherlands

Brazil: see South America

Bulgaria: Philips Bulgaria Ltd., Energoproject, 15th floor, 51 James Bourchier Blvd., 1407 SOFIA, Tel. +359 2 689 211, Fax. +359 2 689 102

Canada: PHILIPS SEMICONDUCTORS/COMPONENTS, Tel. +1 800 234 7381

China/Hong Kong: 501 Hong Kong Industrial Technology Centre, 72 Tat Chee Avenue, Kowloon Tong, HONG KONG, Tel. +852 2319 7888, Fax. +852 2319 7700

Colombia: see South America

Czech Republic: see Austria

Denmark: Prags Boulevard 80, PB 1919, DK-2300 COPENHAGEN S, Tel. +45 32 88 2636, Fax. +45 31 57 0044

Finland: Sinikalliontie 3, FIN-02630 ESPOO, Tel. +358 9 615800, Fax. +358 9 61580920

France: 51 Rue Carnot, BP317, 92156 SURESNES Cedex, Tel. +33 1 40 99 6161, Fax. +33 1 40 99 6427

Germany: Hammerbrookstraße 69, D-20097 HAMBURG, Tel. +49 40 23 53 60, Fax. +49 40 23 536 300

Greece: No. 15, 25th March Street, GR 17778 TAVROS/ATHENS, Tel. +30 1 4894 339/239, Fax. +30 1 4814 240

Hungary: see Austria

India: Philips INDIA Ltd, Band Box Building, 2nd floor, 254-D, Dr. Annie Besant Road, Worli, MUMBAI 400 025, Tel. +91 22 493 8541, Fax. +91 22 493 0966

Indonesia: PT Philips Development Corporation, Semiconductors Division, Gedung Philips, Jl. Buncit Raya Kav.99-100, JAKARTA 12510, Tel. +62 21 794 0040 ext. 2501, Fax. +62 21 794 0080

Ireland: Newstead, Clonskeagh, DUBLIN 14, Tel. +353 1 7640 000, Fax. +353 1 7640 200

Israel: RAPAC Electronics, 7 Kehilat Saloniki St, PO Box 18053, TEL AVIV 61180, Tel. +972 3 645 0444, Fax. +972 3 649 1007

Italy: PHILIPS SEMICONDUCTORS, Piazza IV Novembre 3, 20124 MILANO, Tel. +39 2 6752 2531, Fax. +39 2 6752 2557

Japan: Philips Bldg 13-37, Kohnan 2-chome, Minato-ku, TOKYO 108-8507, Tel. +81 3 3740 5130, Fax. +81 3 3740 5077

Korea: Philips House, 260-199 Itaewon-dong, Yongsan-ku, SEOUL, Tel. +82 2 709 1412, Fax. +82 2 709 1415

Malaysia: No. 76 Jalan Universiti, 46200 PETALING JAYA, SELANGOR, Tel. +60 3 750 5214, Fax. +60 3 757 4880

Mexico: 5900 Gateway East, Suite 200, EL PASO, TEXAS 79905, Tel. +9-5 800 234 7381

Middle East: see Italy

Netherlands: Postbus 90050, 5600 PB EINDHOVEN, Bldg. VB, Tel. +31 40 27 82785, Fax. +31 40 27 88399

New Zealand: 2 Wagener Place, C.P.O. Box 1041, AUCKLAND, Tel. +64 9 849 4160, Fax. +64 9 849 7811

Norway: Box 1, Manglerud 0612, OSLO, Tel. +47 22 74 8000, Fax. +47 22 74 8341

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Poland: Ul. Lukiska 10, PL 04-123 WARSZAWA, Tel. +48 22 612 2831, Fax. +48 22 612 2327

Portugal: see Spain

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Russia: Philips Russia, Ul. Usatcheva 35A, 119048 MOSCOW, Tel. +7 095 755 6918, Fax. +7 095 755 6919

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South Africa: S.A. PHILIPS Pty Ltd., 195-215 Main Road Martindale, 2092 JOHANNESBURG, P.O. Box 7430 Johannesburg 2000, Tel. +27 11 470 5911, Fax. +27 11 470 5494

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Spain: Balmes 22, 08007 BARCELONA, Tel. +34 93 301 6312, Fax. +34 93 301 4107

Sweden: Kottbygatan 7, Akalla, S-16485 STOCKHOLM, Tel. +46 8 5985 2000, Fax. +46 8 5985 2745

Switzerland: Allmendstrasse 140, CH-8027 ZÜRICH, Tel. +41 1 488 2741 Fax. +41 1 488 3263

Taiwan: Philips Semiconductors, 6F, No. 96, Chien Kuo N. Rd., Sec. 1, TAIPEI, Taiwan Tel. +886 2 2134 2865, Fax. +886 2 2134 2874

Thailand: PHILIPS ELECTRONICS (THAILAND) Ltd., 209/2 Sanpavuth-Bangna Road Prakanong, BANGKOK 10260, Tel. +66 2 745 4090, Fax. +66 2 398 0793

Turkey: Talatpasa Cad. No. 5, 80640 GÜLTEPE/ISTANBUL, Tel. +90 212 279 2770, Fax. +90 212 282 6707

Ukraine: PHILIPS UKRAINE, 4 Patrice Lumumba str., Building B, Floor 7, 252042 KIEV, Tel. +380 44 264 2776, Fax. +380 44 268 0461

United Kingdom: Philips Semiconductors Ltd., 276 Bath Road, Hayes, MIDDLESEX UB3 5BX, Tel. +44 181 730 5000, Fax. +44 181 754 8421

United States: 811 East Arques Avenue, SUNNYVALE, CA 94088-3409, Tel. +1 800 234 7381

Uruguay: see South America

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